# SENSITRON SEMICONDUCTOR

# MBR0520L - MBR0540-G

#### SURFACE MOUNT SCHOTTKY BARRIER DIODE

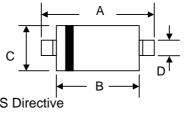
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#### Green Products

SOD-123

#### **Features**

- Low Turn-on Voltage
- Fast Switching
- PN Junction Guard Ring for Transient and ESD Protection
- Designed for Surface Mount Application
- Plastic Material UL Recognition Flammability Classification 94V-O
- Green Products in Compliance with the RoHS Directive



| Dim | Min   | Max  | Min   | Max   |  |  |  |
|-----|-------|------|-------|-------|--|--|--|
| Α   | 3.6   | 3.9  | 0.14  | 0.154 |  |  |  |
| В   | 2.5   | 2.8  | 0.098 | 0.110 |  |  |  |
| C   | 1.4   | 1.8  | 0.055 | 0.070 |  |  |  |
| D   | 0.5   | 0.7  | 0.020 | 0.028 |  |  |  |
| Е   | _     | 0.2  | _     | 0.008 |  |  |  |
| G   | 0.4   | _    | 0.016 |       |  |  |  |
| Н   | 0.95  | 1.35 | 0.037 | 0.053 |  |  |  |
| J   | _     | 0.12 | _     | 0.005 |  |  |  |
|     | In mm |      | In i  | nch   |  |  |  |

### **Mechanical Data**

- Case: SOD-123, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.01 grams (approx.)

## Maximum Ratings @TA=25°C unless otherwise specified

| Characteristic  | Symbol             | MBR0520L    | MBR0530-G | MBR0540-G | Unit |
|---|--------------------|-------------|-----------|-----------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage                                | Vrrm<br>Vrwm<br>Vr | 20          | 30        | 40        | V    |
| RMS Reverse Voltage   | VR(RMS)            | 14          | 21        | 28        | V    |
| Average Rectified Output Current @T <sub>L</sub> = 75°C   | lo                 | 0.5         |           |           | Α    |
| Non-Repetitive Peak Forward Surge Current<br>8.3ms Single half sine-wave superimposed on<br>rated load (JEDEC Method) | IFSM               | 5.5         |           |           | А    |
| Power Dissipation (Note 1)  | Pd                 | 410         |           |           | mW   |
| Typical Thermal Resistance, Junction to Ambient Air (Note 1)  | $R_{\theta}$ JA    | 244         |           |           | °C/W |
| Operating and Storage Temperature Range   | Тj, Tsтg           | -65 to +125 |           |           | °C   |

## Electrical Characteristics @TA=25°C unless otherwise specified

| Characteristic   |                   | Symbol | MBR0520L    | MBR0530-G    | MBR0540-G       | Unit |
|--|-------------------|--------|-------------|--------------|-----------------|------|
| Forward Voltage Drop   | @IF = 0.1A / 0.5A | VFM    | 0.3 / 0.385 | 0.375 / 0.43 | <b>—</b> / 0.51 | V    |
| Peak Reverse Leakage Current<br>@VR = 50% / 100% DC Blocking Voltage |                   | Ігм    | 75 / 250    | 20 / 130     | 10 / 20         | μΑ   |
| Typical Junction Capacitance (VR = 0V DC, f = 1MHz)                  |                   | Cj     | 170         |              |                 | pF   |

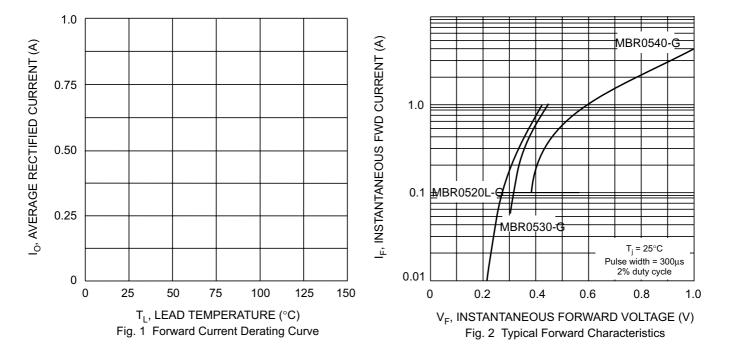
Note: 1. Valid provided that terminals are kept at ambient temperature.

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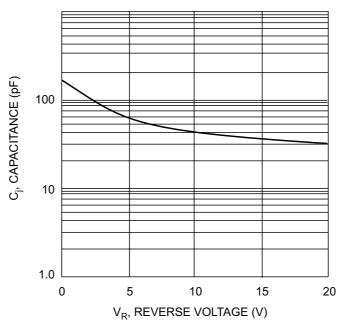


Fig. 3 Typ. Junction Capacitance vs Reverse Voltage

# SENSITRON

### **SEMICONDUCTOR**

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